

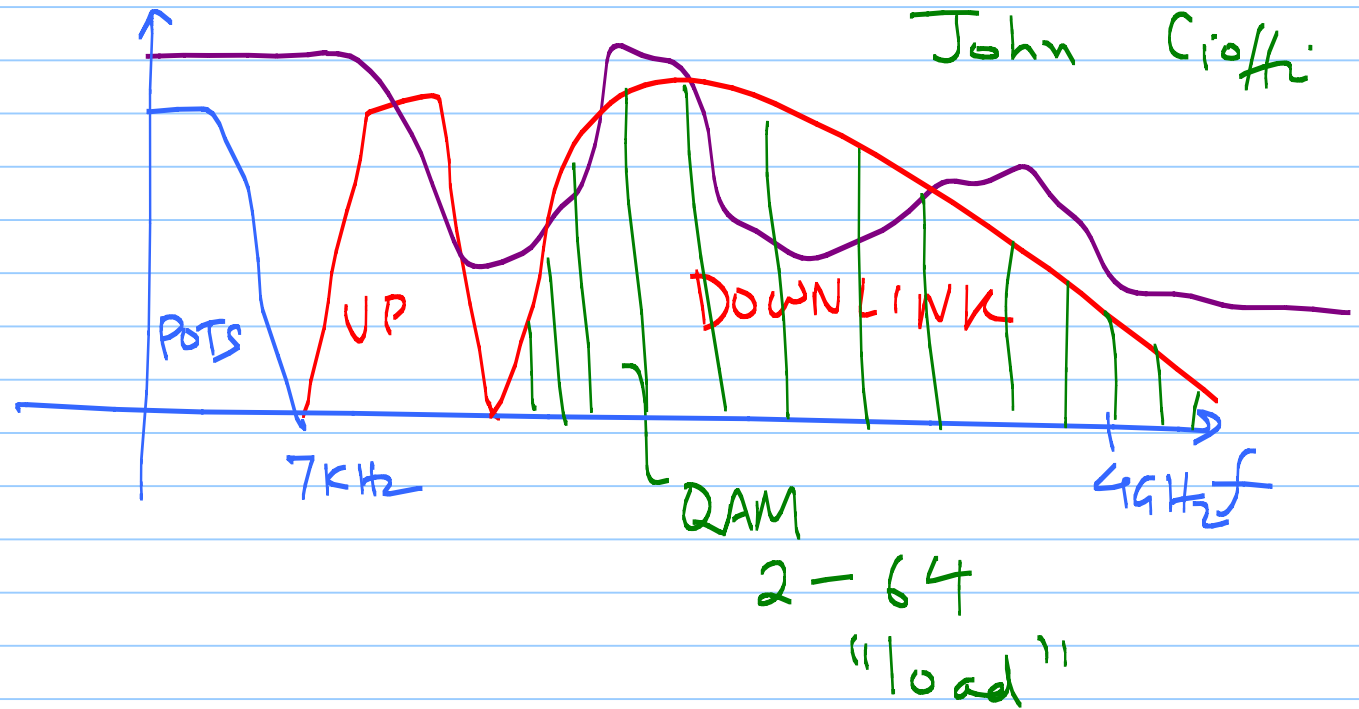
ECE 5411 - Lecture 9

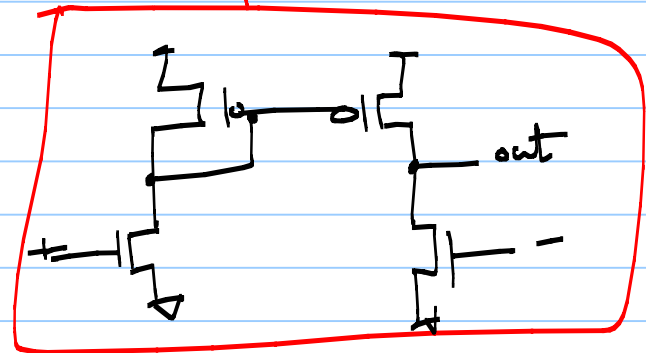
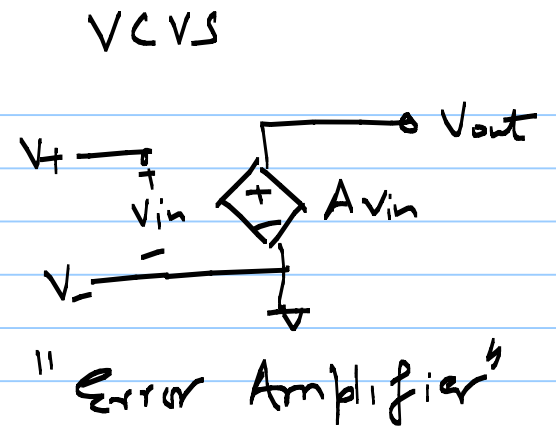
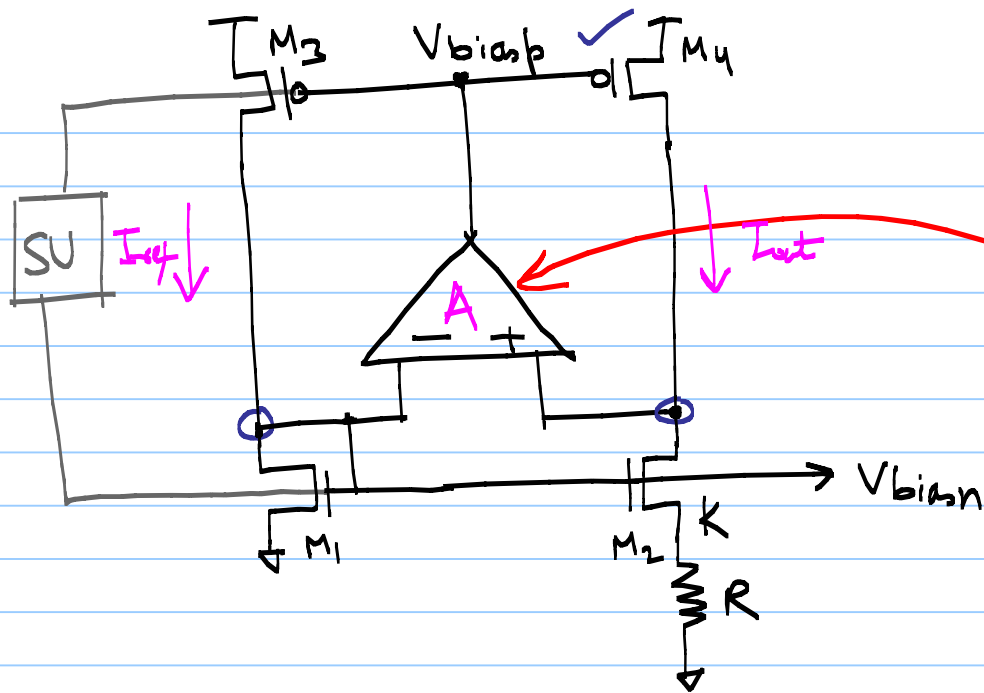
Note Title

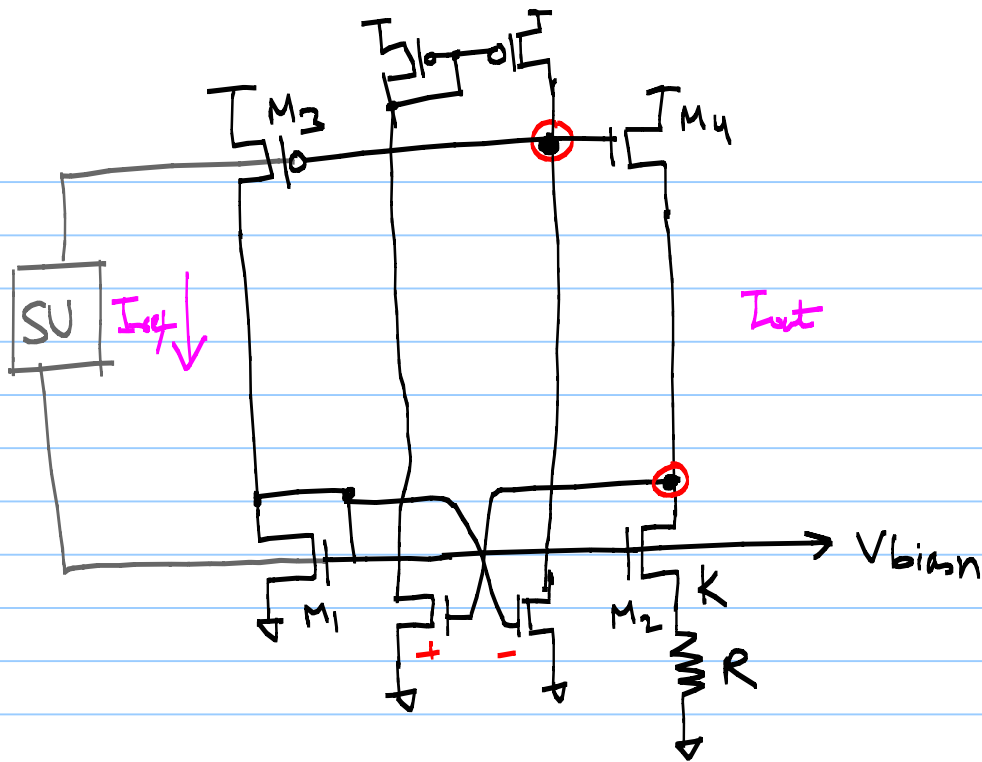
2/16/2011

ASIDE

ADSL







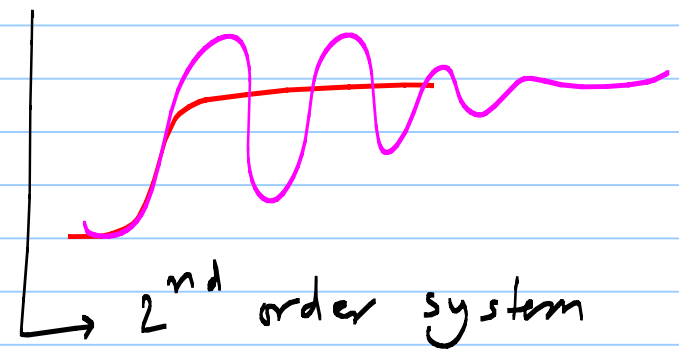
Modify $\rightarrow$ get rid of one of the r_{i-Z} node

r_o
Hi-Z

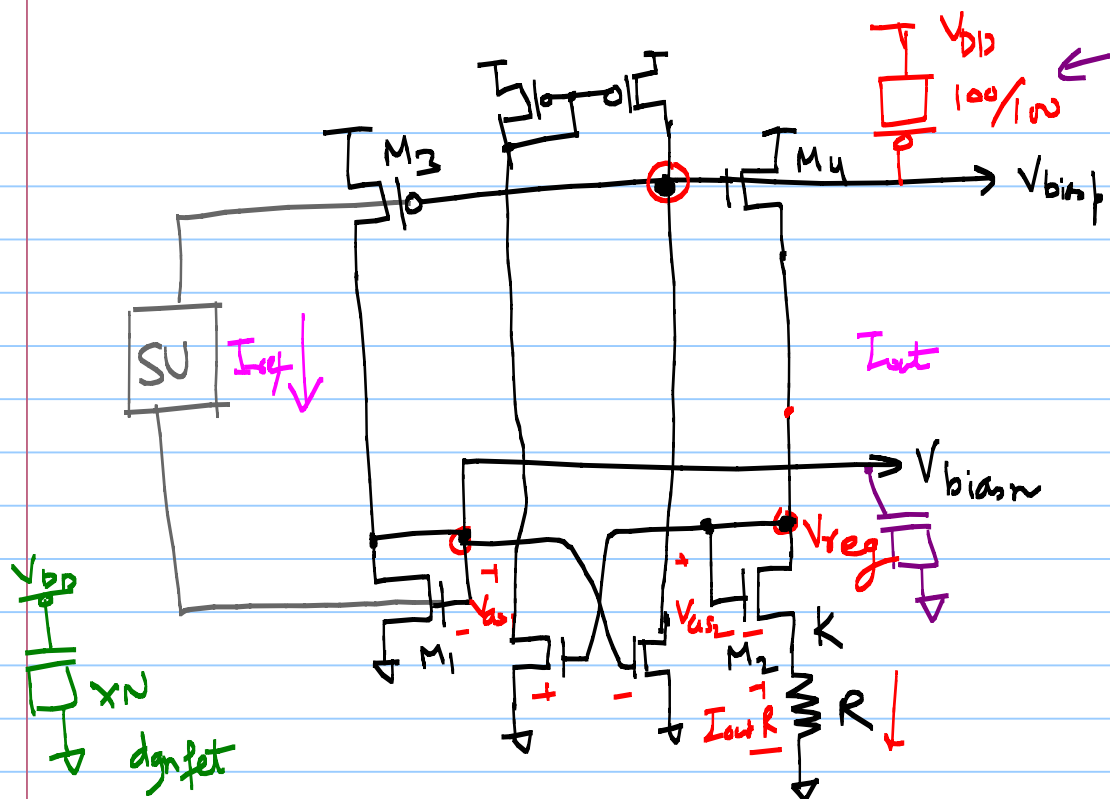
$\frac{1}{g_m}$
Lo-Z

2- r_{i-Z} (high impedance)

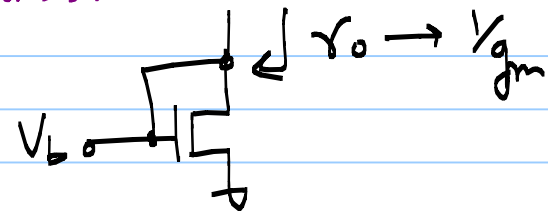
"COMPENSATION"



2- dominant poles



Compensation Caps



$$V_{as1} = V_{as2} + I_{out} R$$

for large A

$\rightarrow I_{out}$ is independent of V_{DD} .

1st order system

$\rightarrow$ loop-gain is reduced due to diode-connected MOSFET.

Digression

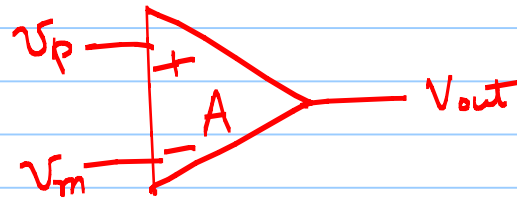


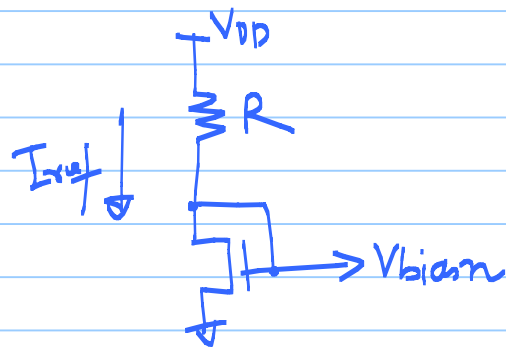
Fig. 20.23 & 20.24

$$v_{out} = A(v_p - v_m)$$

↓ ↓
finite $\infty \times (0)$
value

$$A \rightarrow \infty \Rightarrow v_p \stackrel{\Delta}{=} v_m$$

Temperature Behavior of Current references



$$I_{ref} = \frac{V_{DD} - V_{GS}}{R}$$

$$\frac{\partial I_{ref}}{\partial T} = - \frac{(V_{DD} - V_{GS})}{R^2} \cdot \frac{\partial R}{\partial T} - \frac{1}{R} \cdot \frac{\partial V_{GS}}{\partial T}$$

$$= - \frac{I_{ref}}{R} \cdot \frac{\partial R}{\partial T} - \frac{1}{R} \cdot \frac{\partial V_{GS}}{\partial T}$$

$$TC_{I_{ref}} = \frac{\left(\frac{\partial I_{ref}}{\partial T} \right)}{I_{ref}} = \underbrace{- \frac{1}{R} \cdot \frac{\partial R}{\partial T}}_{TC_R} - \underbrace{\frac{1}{(V_{DD} - V_{GS})} \cdot \frac{\partial V_{GS}}{\partial T}}_{\text{changes with operating point}}$$

changes with operating point

BMR

$$I_{ref} = \frac{2}{R^2 K P_n \frac{W}{L}} \left(1 - \frac{1}{\sqrt{K}}\right)^2 \rightarrow \alpha$$

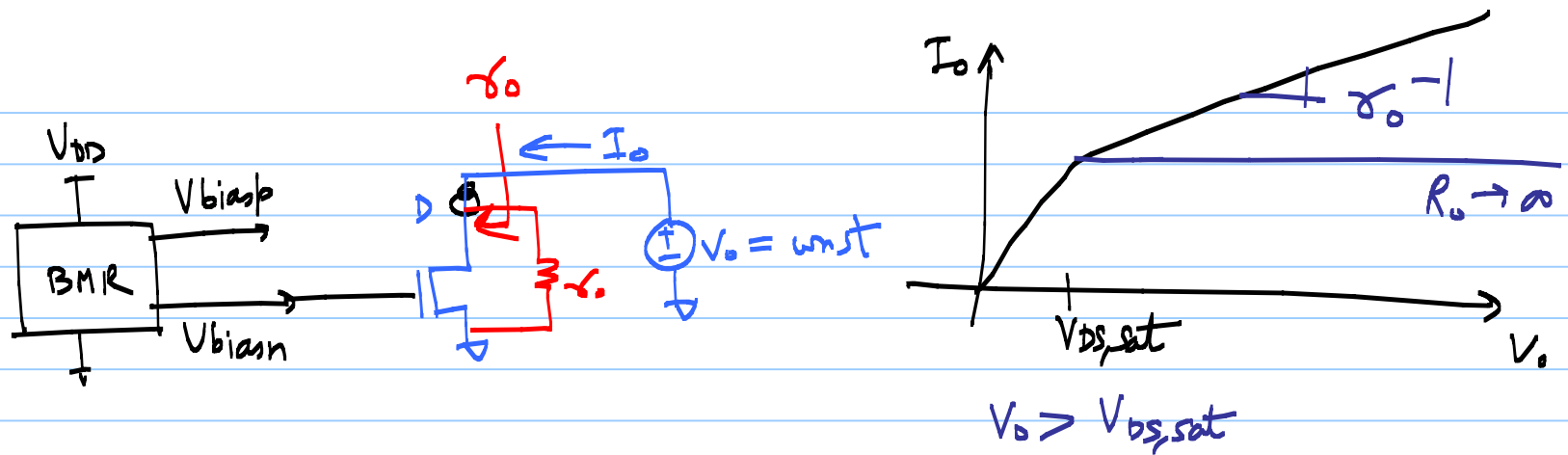
$$\frac{\partial I_{ref}}{\partial T} = \frac{-4\alpha}{R^3 K P_n \frac{W}{L}} \cdot \frac{\partial R}{\partial T} - \frac{2\alpha}{R^2 K P_n^2 \frac{W}{L}} \frac{\partial K P_n}{\partial T}$$

$$TC_{I_{ref}} = \frac{\left(\frac{\partial I_{ref}}{\partial T}\right)}{I_{ref}} = -2 \left(\frac{1}{R} \cdot \frac{\partial R}{\partial T} \right) - \frac{1}{K P_n} \frac{\partial K P_n}{\partial T}$$

$$= -2 \underbrace{TC_R}_{\substack{\uparrow 1000 \text{ ppm}/^\circ\text{C} \\ +ve}} - \underbrace{TC_{KP_n}}_{\substack{-ve \\ +ve}} \quad \frac{1.5}{T} = \frac{1.5}{300}$$

Band gap References
(BGR)

$$= -0.004 + \frac{1.5}{300} = 1000 \text{ ppm}/^\circ\text{C}$$

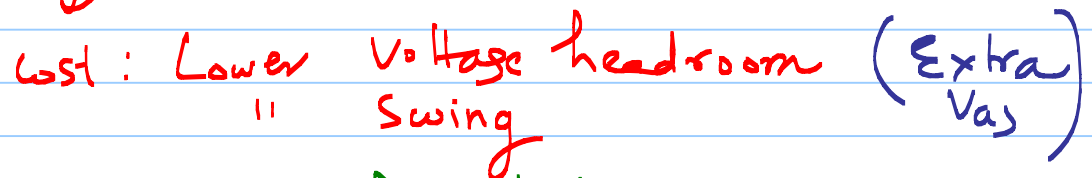
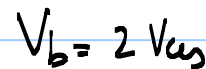


* We want the output resistance (R_o) of the current mirror to be very high

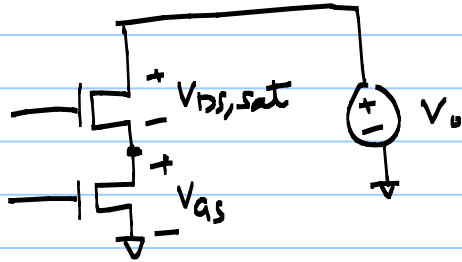
↳ so that it behaves like an ideal current source.

* In other words, if we can hold V_{DS} of the current mirror, then I_o will not vary much.

I_o is fixed by the bottom devices only



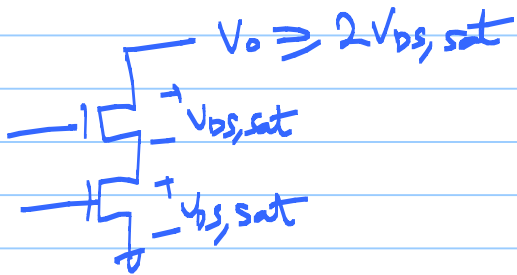
- * Even if M_3 & M_4 have body-effect $\rightarrow$ the drains of M_1 & M_2 are held together

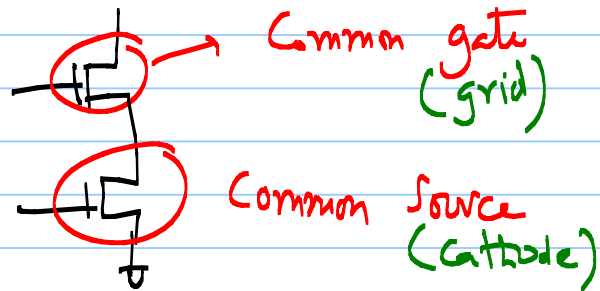


$$V_o \geq V_{gs} + V_{DS,sat}$$

$$\equiv \underline{\underline{V_{THN}}} + \underline{2V_{DS,sat}}$$

* we are wasting one V_{THN} !





CASCODE = Cascade of Common Cathode & Common Grid amplifier.